



MAXIMUM RATINGS (T_A=25°C)

| | SYMBOL | UNITS |
|---------------------------|-----------------------------------|-------|
| Collector-Base Voltage | V _{CBO} | V |
| Collector-Emitter Voltage | V _{CEO} | V |
| Emitter-Base Voltage | V _{EBO} | V |
| Collector Current | I _C | mA |
| Power Dissipation | P _D | W |
| Operating and Storage | | |
| Junction Temperature | T _J , T _{stg} | °C |
| Thermal Resistance | Θ _{JA} | °C/W |

ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted)

| SYMBOL | TEST CONDITIONS | MIN | MAX | UNITS |
|----------------------|--|-----|-----|-------|
| I _{CBO} | V _{CB} =60V | | 10 | nA |
| I _{CBO} | V _{CB} =60V, T _A =125°C | | 10 | µA |
| I _{EBO} | V _{EB} =3.0V | | 10 | nA |
| I _{CEV} | V _{CE} =60V, V _{EB} =3.0V | | 10 | nA |
| BV _{CBO} | I _C =10µA | 75 | | V |
| BV _{CEO} | I _C =10mA | 40 | | V |
| BV _{EBO} | I _E =10µA | 6.0 | | V |
| V _{CE(SAT)} | I _C =150mA, I _B =15mA | | 0.3 | V |
| V _{CE(SAT)} | I _C =500mA, I _B =50mA | | 1.0 | V |
| V _{BE(SAT)} | I _C =150mA, I _B =15mA | 0.6 | 1.2 | V |
| V _{BE(SAT)} | I _C =500mA, I _B =50mA | | 2.0 | V |
| h _{FE} | V _{CE} =10V, I _C =0.1mA | 35 | | |
| h _{FE} | V _{CE} =10V, I _C =1.0mA | 50 | | |
| h _{FE} | V _{CE} =10V, I _C =10mA | 75 | | |
| h _{FE} | V _{CE} =10V, I _C =150mA | 100 | 300 | |
| h _{FE} | V _{CE} =1.0V, I _C =150mA | 50 | | |
| h _{FE} | V _{CE} =10V, I _C =500mA | 40 | | |
| f _T | V _{CE} =20V, I _C =20mA, f=100MHz | 300 | | MHz |
| C _{ob} | V _{CB} =10V, I _E =0, f=1.0MHz | | 8.0 | pF |
| C _{ib} | V _{EB} =0.5V, I _C =0, f=1.0MHz | | 25 | pF |

CentralTM
Semiconductor Corp.

DESCRIPTION:

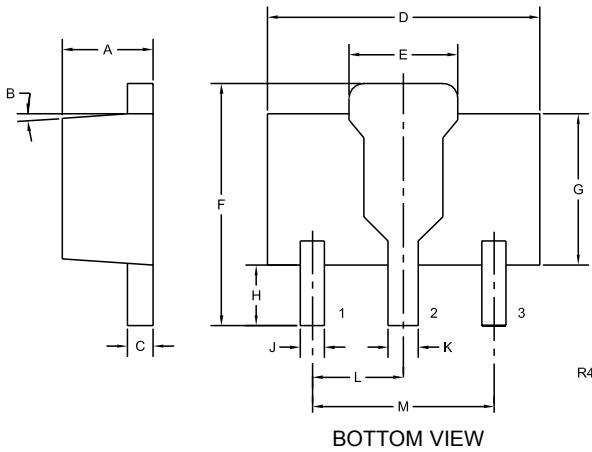
The CENTRAL SEMICONDUCTOR CXT2222A type is an NPN silicon transistor manufactured by the epitaxial planar process, epoxy molded in a surface mount package, designed for small signal general purpose and switching applications.

MARKING CODE: FULL PART NUMBER

ELECTRICAL CHARACTERISTICS (Continued)

| SYMBOL | TEST CONDITIONS | MIN | MAX | UNITS |
|------------|--|------|------|------------------|
| h_{ie} | $V_{CE}=10V, I_C=1.0mA, f=1.0kHz$ | 2.0 | 8.0 | kΩ |
| h_{re} | $V_{CE}=10V, I_C=10mA, f=1.0kHz$ | 0.25 | 1.25 | kΩ |
| h_{re} | $V_{CE}=10V, I_C=1.0mA, f=1.0kHz$ | | 8.0 | $\times 10^{-4}$ |
| h_{re} | $V_{CE}=10V, I_C=10mA, f=1.0kHz$ | | 4.0 | $\times 10^{-4}$ |
| h_{fe} | $V_{CE}=10V, I_C=1.0mA, f=1.0kHz$ | 50 | 300 | |
| h_{fe} | $V_{CE}=10V, I_C=10mA, f=1.0kHz$ | 75 | 375 | |
| h_{oe} | $V_{CE}=10V, I_C=1.0mA, f=1.0kHz$ | 5.0 | 35 | μmhos |
| h_{oe} | $V_{CE}=10V, I_C=10mA, f=1.0kHz$ | 25 | 200 | μmhos |
| $r_b' C_c$ | $V_{CB}=10V, I_E=20mA, f=31.8MHz$ | | 150 | ps |
| NF | $V_{CE}=10V, I_C=100\mu A, R_S=1.0k\Omega, f=1.0kHz$ | | 4.0 | dB |
| t_d | $V_{CC}=30V, V_{BE}=0.5, I_C=150mA, I_{B1}=15mA$ | | 10 | ns |
| t_r | $V_{CC}=30V, V_{BE}=0.5, I_C=150mA, I_{B1}=15mA$ | | 25 | ns |
| t_s | $V_{CC}=30V, I_C=150mA, I_{B1}=I_{B2}=15mA$ | | 225 | ns |
| t_f | $V_{CC}=30V, I_C=150mA, I_{B1}=I_{B2}=15mA$ | | 60 | ns |

SOT-89 CASE - MECHANICAL OUTLINE



| SYMBOL | DIMENSIONS | | INCHES | | MILLIMETERS | |
|--------|------------|-------|-----------|------|-------------|-----|
| | MIN | MAX | MIN | MAX | MIN | MAX |
| A | 0.055 | 0.067 | 1.40 | 1.70 | | |
| B | 4° | | 4° | | | |
| C | 0.014 | 0.018 | 0.35 | 0.46 | | |
| D | 0.173 | 0.185 | 4.40 | 4.70 | | |
| E | 0.064 | 0.074 | 1.62 | 1.87 | | |
| F | 0.146 | 0.177 | 3.70 | 4.50 | | |
| G | 0.090 | 0.106 | 2.29 | 2.70 | | |
| H | 0.028 | 0.051 | 0.70 | 1.30 | | |
| J | 0.014 | 0.019 | 0.36 | 0.48 | | |
| K | 0.017 | 0.023 | 0.44 | 0.58 | | |
| L | 0.059 | | 1.50 | | | |
| M | 0.118 | | 3.00 | | | |

SOT-89 (REV: R4)

LEAD CODE:

- 1) Emitter
- 2) Collector
- 3) Base

MARKING CODE:
FULL PART NUMBER